

GUJARAT TECHNOLOGICAL UNIVERSITY
BE - SEMESTER-VII(NEW) EXAMINATION – SUMMER 2019

Subject Code:2171001

Date:10/05/2019

Subject Name: Microwave Engineering

Time:02:30 PM TO 05:00 PM

Total Marks: 70

Instructions:

1. Attempt all questions.
2. Make suitable assumptions wherever necessary.
3. Figures to the right indicate full marks.

			MARKS
Q.1	(a)	List the microwave frequency bands.	3
	(b)	How microwave signals and systems are different than other low frequency signals and systems?	4
	(c)	Explain the necessity of impedance matching and methods to perform impedance matching.	7
Q.2	(a)	A 75Ω transmission line that is half wavelength long is terminated in a load resistance of 300Ω . Determine its input impedance.	3
	(b)	Explain the waveguide parameters (a) cut-off wavelength (b) guide length	4
	(c)	Derive transmission line equations and also derive solution of transmission line equation.	7
OR			
Q.3	(c)	Explain the construction and applications of smith chart.	7
	(a)	Draw the different type of modes in waveguides.	3
	(b)	Explain the waveguide parameters : group and phase velocities, characteristic wave impedance.	4
	(c)	Find all possible modes that will propagate in a rectangular waveguide having cross-sectional dimensions of $4\text{cm} \times 2\text{cm}$. the operating frequency is 5GHz.	7
OR			
Q.3	(a)	Compare transmission lines with waveguides.	3
	(b)	Write short note on scattering parameters.	4
	(c)	Draw diagram of E-plane Tee junction and derive s-parameter matrix for the same.	7
Q.4	(a)	Explain directional coupler parameters.	3
	(b)	Write a short note on Varactor diode.	4
	(c)	Write short note on tunnel diode.	7
OR			
Q.4	(a)	Define Q-factor of a cavity resonator.	3
	(b)	Write short note on isolators.	4
	(c)	Define Klystron. Write short notes Two Cavity Klystron.	7

- Q.5**
- (a) A certain microstrip line has the following parameters: $\epsilon_r = 5.23$, $h = 7\text{mm}$, $t = 2.8\text{mm}$, $w = 10\text{mm}$. Calculate the characteristic impedance z_0 of the line. **3**
 - (b) Write the applications and advantages of microwave solid state devices. **4**
 - (c) Explain Electromagnetic Interference and Microwave Imaging. **7**

OR

- Q.5**
- (a) An n-type GaAs Gunn diode has electron density of 10^{18}cm^{-3} , temperature of 300^0K , electron density at lower valley is 10^{10}cm^{-3} and electron density at upper valley is 10^8cm^{-3} . Determine the conductivity of the diode. Take $\mu_l = 8000\text{ cm}^2/\text{V-sec}$ and $\mu_u = 180\text{ cm}^2/\text{V-sec}$. **3**
 - (b) Explain the Gunn effect. **4**
 - (c) Describe Microwave RADAR system. **7**

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